

INFORMATION DISCLOSURE CITATION IN AN APPLICATION (PTO-1449)			ATTY. DOCKET NO. 57810-084		SERIAL NO. Divisional of Appl No. 10/084,050 <i>10/796154</i>				
			APPLICANT Nobuhiko HAYASHI, et al.						
			FILING DATE March 10, 2004		GROUP 2818				
U.S. PATENT DOCUMENTS									
EXAMINER'S INITIALS <i>Dle</i>	CITE NO.	Document Number		Publication Date	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear			
		Number-Kind Code(s) (if known)		MM-DD-YYYY					
		US	6,015,979	1/18/2000	Sugiura et al.				
		US	6,051,849	4/18/2000	Davis et al.				
		US	6,503,769	01/07/2003	Nakamura et al.				
		US							
FOREIGN PATENT DOCUMENTS									
EXAMINER'S INITIALS <i>Dle</i>	CITE NO.	Foreign Patent Document		Publication Date	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines Where Relevant Figures Appear	Translation		
		Country Code(s) - Number - Kind Code(s) (if known)		MM-DD-YYYY				Yes	No
		2000-164989		6/16/2000			Japan (w/ English Abstract)		
		2000-269144		9/29/2000			Japan (w/ English Abstract)		
		2000-21789		1/21/2000			Japan (w/ English Abstract)		
		10-312971		11/24/1998			Japan (w/ English Abstract)		
OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)									
EXAMINER'S INITIALS <i>Dle</i>	CITE NO.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.							
		S. Nakamura et al., "Long lifetime violet InGaIn/GaN/A1GaIn-based semiconductor lasers", Journal of Oyo Denshi Bussai Bunkakai, Vol. 4, (1998), pp. 53-58 and 210-215.							
		Akira Usui et al., "Thick GaIn Epitaxial Growth with Low Dislocation Density by Hydride Vapor Phase Epitaxy", Jpn. J. Appl. Phys. Vol. 36 (1997), pp. L899-L902.							
		Kevin Linthicum et al., "Pendeoepitaxy of gallium nitride thin films", Applied Physics Letter, Vol. 75, No. 2, July 12, 1999, pp. 196-198.							
		Isao Kidoguchi et al., "Air-bridged lateral epitaxial overgrowth of GaIn thin films", Applied Physics Letter, Vol. 76, No. 25, June 19, 2000, pp. 3768-3770.							
EXAMINER <i>Dle</i>				DATE CONSIDERED <i>OCT - 2005</i>					

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

1 Applicant's unique citation designation number (optional). 2 Applicant is to place a check mark here if English language Translation is attached.